

Product data sheet

1. General description

Ultrafast power diode in a SOD59 (2-lead TO-220AC) plastic package.

2. Features and benefits

- Fast switching
- Low leakage current
- Low forward voltage drop
- Low thermal resistance
- Soft recovery characteristic

3. Applications

- High frequency switched-mode power supplies
- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)

4. Quick reference data

Table 1. Qui	ck reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	-	600	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} ≤ 109 °C; square-wave pulse; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>	-	-	10	A
Static character	eristics					
V _F	forward voltage	I _F = 10 A; T _j = 150 °C; <u>Fig. 6</u>	-	-	1.6	V
Dynamic chara	acteristics	·				
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	20	-	ns





5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	K A
2	А	anode	$2 \circ 4$	001aaa020
mb	mb	mounting base; connected to cathode	C C C C C C C C C C C C C C C C C C C	

6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
BYV10-600P	TO-220AC	plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC	SOD59				

7. Marking

Table 4. Marking codes	
Type number	Marking code
BYV10-600P	BYV10-600P

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{RRM}	repetitive peak reverse voltage		-	600	V
V _{RWM}	crest working reverse voltage		-	600	V
V _R	reverse voltage	DC	-	600	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} ≤ 109 °C; square-wave pulse; <u>Fig. 1; Fig. 2; Fig. 3</u>	-	10	A
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 μs; T _{mb} ≤ 109 °C; square-wave pulse	-	20	A
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Ultrafast power diode

Symbol	Parameter	Conditions	Min	Мах	Unit
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	-	80	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	-	88	A
T _{stg}	storage temperature		-65	175	°C
Tj	junction temperature		-	175	°C

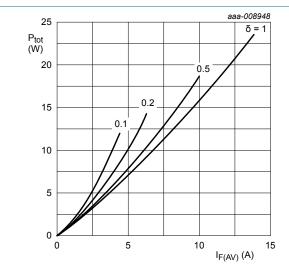
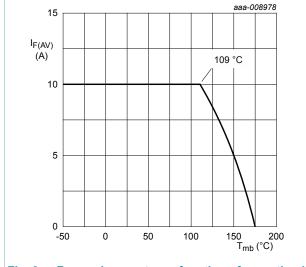


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

$I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$
$V_{O} = 1.268 \text{ V}; R_{S} = 0.031 \Omega$





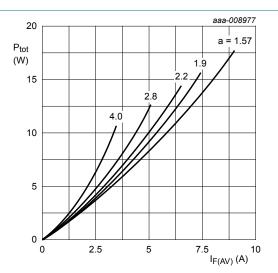
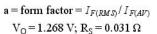
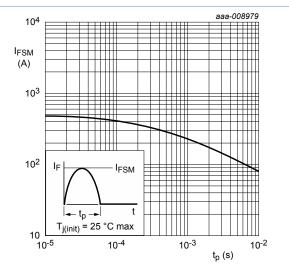


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values



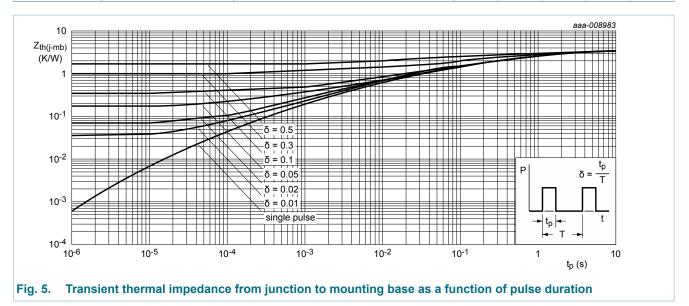


4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

Ultrafast power diode

9. Thermal characteristics

Table 6. The	ermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 5	-	-	3.5	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	60	-	K/W



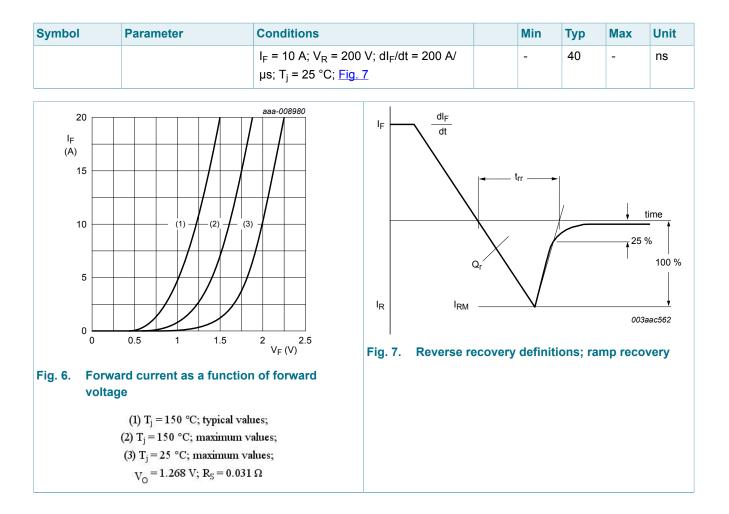
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Static chara	acteristics	· · · · ·				-,
V _F	forward voltage	I _F = 10 A; T _j = 25 °C; <u>Fig. 6</u>	-	1.5	2	V
		I _F = 10 A; T _j = 150 °C; <u>Fig. 6</u>	-	-	1.6	V
I _R re	reverse current	V _R = 600 V; T _j = 25 °C	-	-	10	μA
		V _R = 500 V; T _j = 150 °C	-	-	250	μA
Dynamic ch	aracteristics					
t _{rr} reverse recove	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	35	50	ns
		I _F = 1 A; V _R = 30 V; dI _F /dt = 100 A/μs; T _j = 25 °C; <u>Fig. 7</u>	-	20	-	ns

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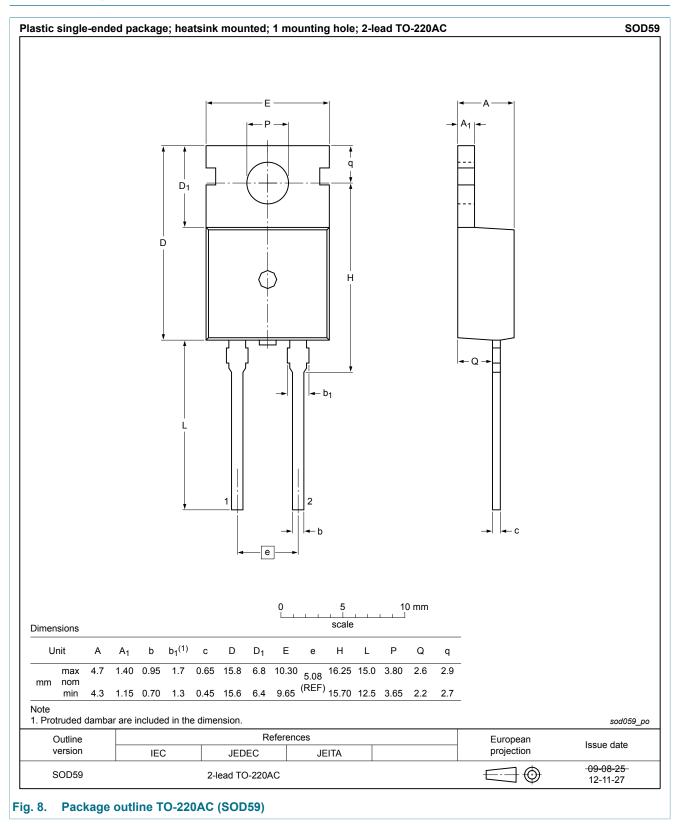
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11. Package outline



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Ultrafast power diode

12. Legal information

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Ultrafast power diode

13. Contents

1	General description	1
2	Features and benefits	1
3	Applications	. 1
4	Quick reference data	1
5	Pinning information	2
6	Ordering information	2
7	Marking	. 2
8	Limiting values	2
9	Thermal characteristics	4
10	Characteristics	4
11	Package outline	. 6
12	Legal information	7
12.1	Data sheet status	7
12.2	Definitions	7
12.3	Disclaimers	7
12.4	Trademarks	. 8

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